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Kind regards,

Team Nexperia





Product data sheet

1. Product profile

1.1 General description

NPN/PNP transistor pair connected as push-pull driver in a SOT457 (SC-74) Surface-Mounted Device (SMD) plastic package.

1.2 Features

- Switching transistors in push-pull configuration
- Application-optimized pinout
- Space-saving solution
- Internal connections to minimize layout effort
- Reduces component count

1.3 Applications

- MOSFET driver
- Power bipolar transistor driver
- Output current booster for operational amplifier

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Per transis	stor; for the PNP transistor	with negative pola	rity			
V _{CEO}	collector-emitter voltage	open base	-	-	40	V
l _C	collector current		-	-	0.6	А
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms	-	-	1	A



2. Pinning information

Table 2.	Pinning		
Pin	Description	Simplified outline	Symbol
1	base TR1, TR2		
2	collector TR2		
3	collector TR2	0	
4	emitter TR1, TR2		
5	collector TR1		
6	collector TR1		1 1 1 1 2 3 <i>006aaa659</i>

3. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
PMD2001D	SC-74	plastic surface-mounted package (TSOP6); 6 leads	SOT457			

4. Marking

Table 4. Marking codes	
Type number	Marking code
PMD2001D	9E

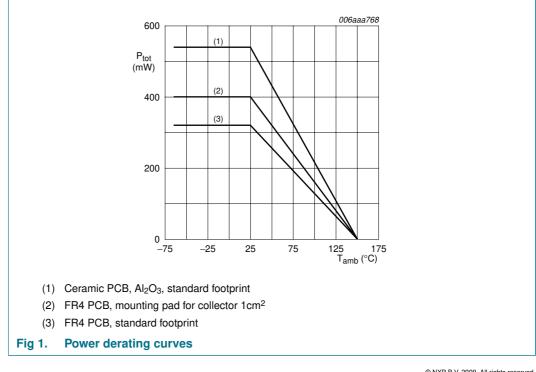
5. Limiting values

Symbol	Parameter	Conditions	Min	Max	Unit
Per transis	stor; for the PNP transistor w	vith negative polari	ty		
V _{CBO}	collector-base voltage	open emitter	-	40	V
V _{CEO}	collector-emitter voltage	open base	-	40	V
I _C	collector current		-	0.6	А
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms	-	1	А
I _{BM}	peak base current		-	0.1	А
		single pulse; t _p ≤ 1 ms	-	0.2	A
Per device)				
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	[1] -	320	mW
			[2] _	400	mW
			[3] _	540	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1cm².

[3] Device mounted on a ceramic PCB, AI_2O_3 , standard footprint.



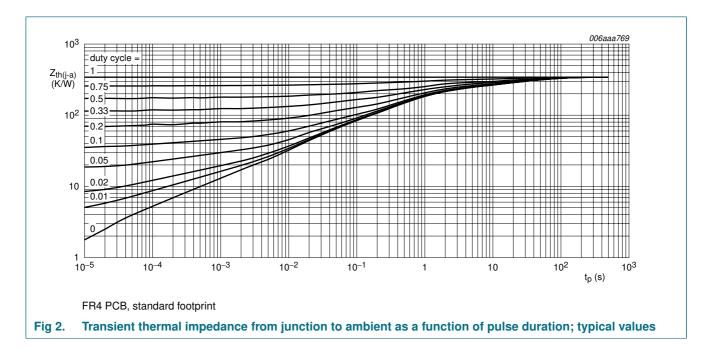
6. Thermal characteristics

Table 6.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j\text{-}a)} \qquad \mbox{thermal resistance from} \\ junction to ambient$	thermal resistance from	in free air	<u>[1]</u> _	-	390	K/W
	junction to ambient		[2] _	-	315	K/W
			<u>[3]</u>	-	230	K/W

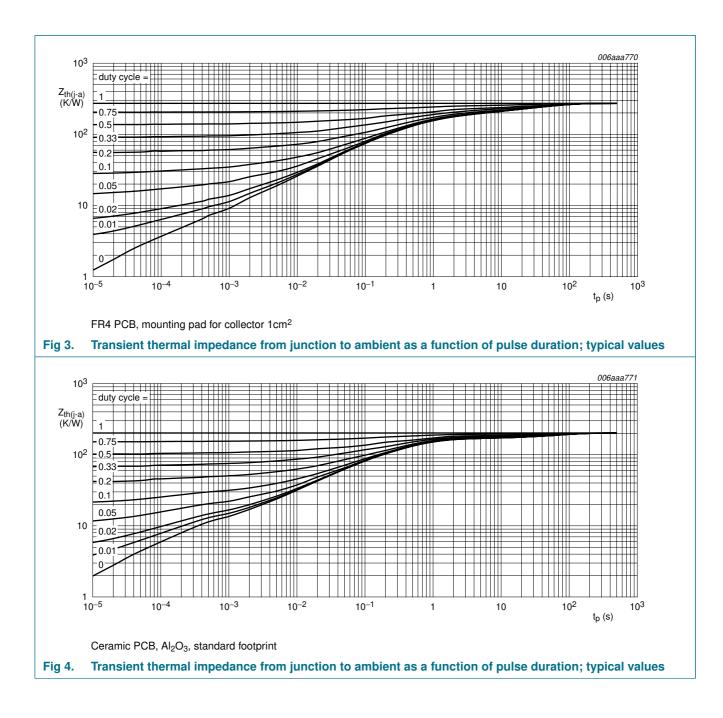
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

[3] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.



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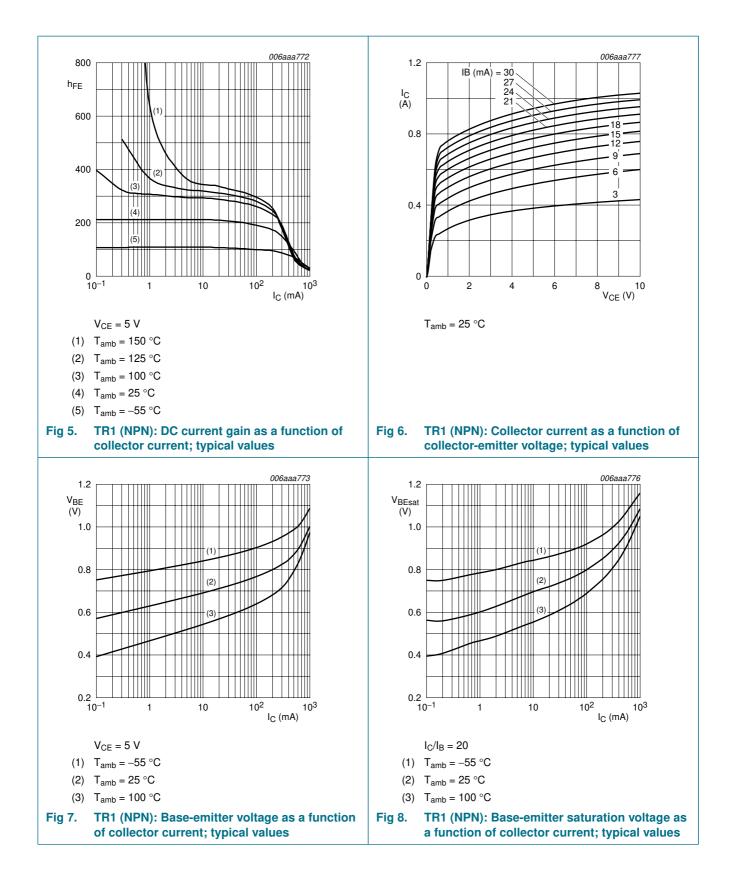


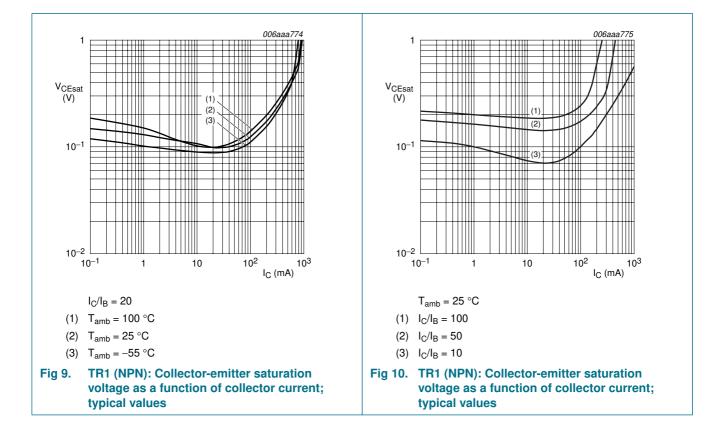
7. Characteristics

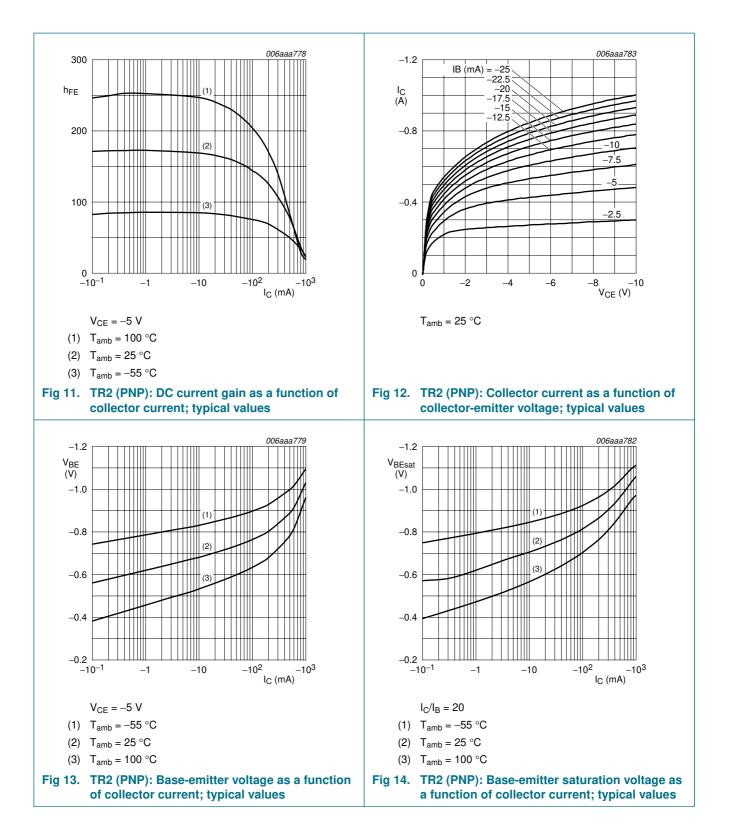
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per NPN	l transistor						
I _{CBO}	collector-base cut-off	$V_{CB} = 40 \text{ V}; \text{ I}_{E} = 0 \text{ A}$		-	-	10	nA
	current	$V_{CB} = 40 \text{ V}; I_E = 0 \text{ A};$ T _j = 150 °C		-	-	10	μA
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 1 \text{ mA}$		100	210	-	
		$V_{CE} = 5 \text{ V}; I_{C} = 200 \text{ mA}$		100	170	300	
		$V_{CE} = 5 \text{ V}; I_{C} = 500 \text{ mA}$	[1]	50	100	-	
V _{CEsat}	collector-emitter	$I_{C} = 200 \text{ mA}; I_{B} = 20 \text{ mA}$		-	150	250	mV
saturation voltage	saturation voltage	$I_{C} = 500 \text{ mA}; I_{B} = 50 \text{ mA}$	[1]	-	300	500	mV
V _{BEsat}	/ _{BEsat} base-emitter	$I_{C} = 200 \text{ mA}; I_{B} = 20 \text{ mA}$		-	0.86	1	V
	saturation voltage	$I_{C} = 500 \text{ mA}; I_{B} = 50 \text{ mA}$	[1]	-	0.95	1.1	V
Per PNF	P transistor						
I _{CBO}	I _{CBO} collector-base cut-off current	$V_{CB} = -40 \text{ V}; \text{ I}_{E} = 0 \text{ A}$		-	-	-10	nA
		$\label{eq:VCB} \begin{array}{l} V_{CB} = -40 \ V; \ I_E = 0 \ A; \\ T_j = 150 \ ^\circ C \end{array}$		-	-	-10	μA
h _{FE}	DC current gain	$V_{CE} = -5 \text{ V}; I_C = -1 \text{ mA}$		100	180	-	
		$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -200 \text{ mA}$		80	125	300	
		V_{CE} = -5 V; I_{C} = $-500\ mA$	[1]	50	80	-	
V _{CEsat}	collector-emitter	$I_C = -200 \text{ mA}; I_B = -20 \text{ mA}$		-	-130	-250	mV
	saturation voltage	$I_C = -500 \text{ mA}; I_B = -50 \text{ mA}$	[1]	-	-280	-500	mV
V _{BEsat}	base-emitter	$I_C = -200 \text{ mA}; I_B = -20 \text{ mA}$		-	-0.87	-1	V
	saturation voltage	$I_C = -500 \text{ mA}; I_B = -50 \text{ mA}$	[1]	-	-0.98	-1.1	V
Per dev	ice						
t _d	delay time	$I_{C} = 0.15 \text{ A}; V_{I} = 7.5 \text{ V}$		-	3	-	ns
t _r	rise time			-	3	-	ns
t _{on}	turn-on time			-	6	-	ns
t _s	storage time			-	2	-	ns
t _f	fall time			-	3	-	ns
t _{off}	turn-off time			-	5	-	ns

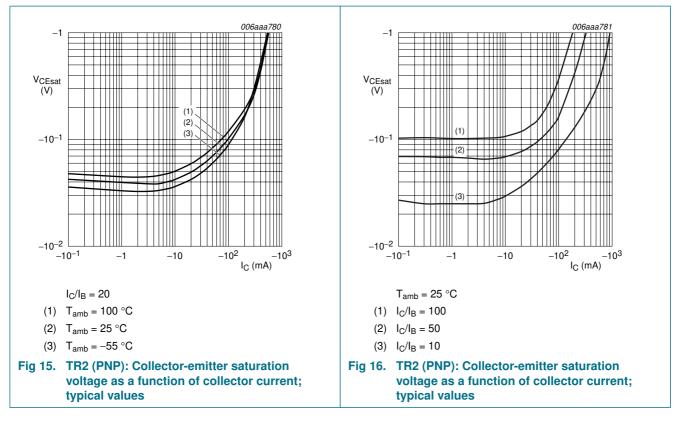
[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$

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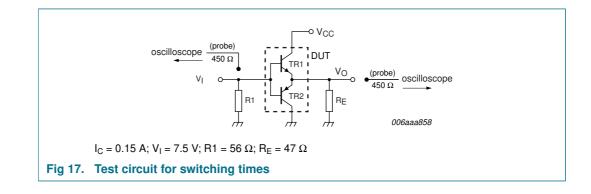




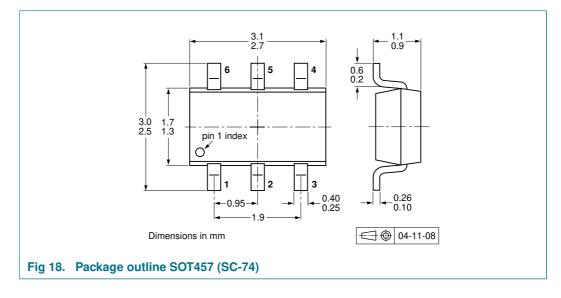




8. Test information



9. Package outline



10. Packing information

Table 8.Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

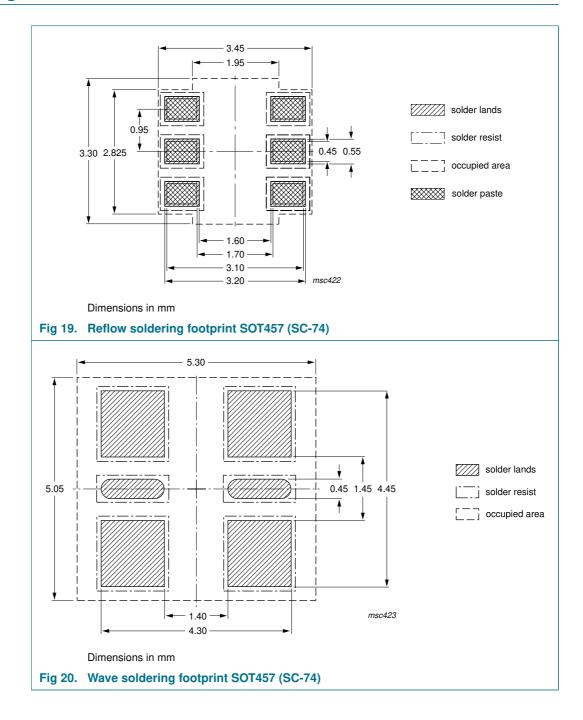
Type number	Package	Description	Packing	g quantity
			3000	10000
PMD2001D SOT457	4 mm pitch, 8 mm tape and reel; T1	2 -115	-135	
		4 mm pitch, 8 mm tape and reel; T2	<u>3</u> -125	-165

[1] For further information and the availability of packing methods, see <u>Section 14</u>.

[2] T1: normal taping

[3] T2: reverse taping

11. Soldering



12. Revision history

Table 9. Revisio	n history			
Document ID	Release date	Data sheet status	Change notice	Supersedes
PMD2001D_2	20090828	Product data sheet	-	PMD2001D_1
Modifications:		neet was changed to reflec w legal definitions and dis		
	 Figure 20 "V 	Vave soldering footprint SC	<u> </u>	d
PMD2001D_1	20060925	Product data sheet	-	-

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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